

2SK1907

# **Ultrahigh-Speed Switching Applications**

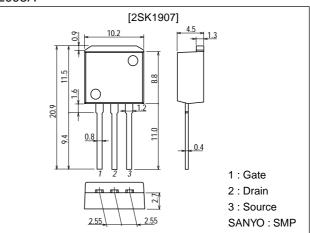
## Features

- $\cdot$  Low ON resistance.
- $\cdot$  Ultrahigh-speed switching.
- · Low-voltage drive.
- Surface mount type device making the following possible.
- Reduction in the number of manufacturing processes for 2SK1907-applied equipment.
- · High density surface mount applications.
- · Small size of 2SK1907-applied equipment.

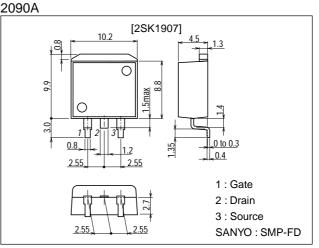
## **Package Dimensions**

## unit:mm

#### 2093A



## unit:mm



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# Specifications

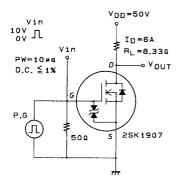
## Absolute Maximum Ratings at $Ta = 25^{\circ}C$

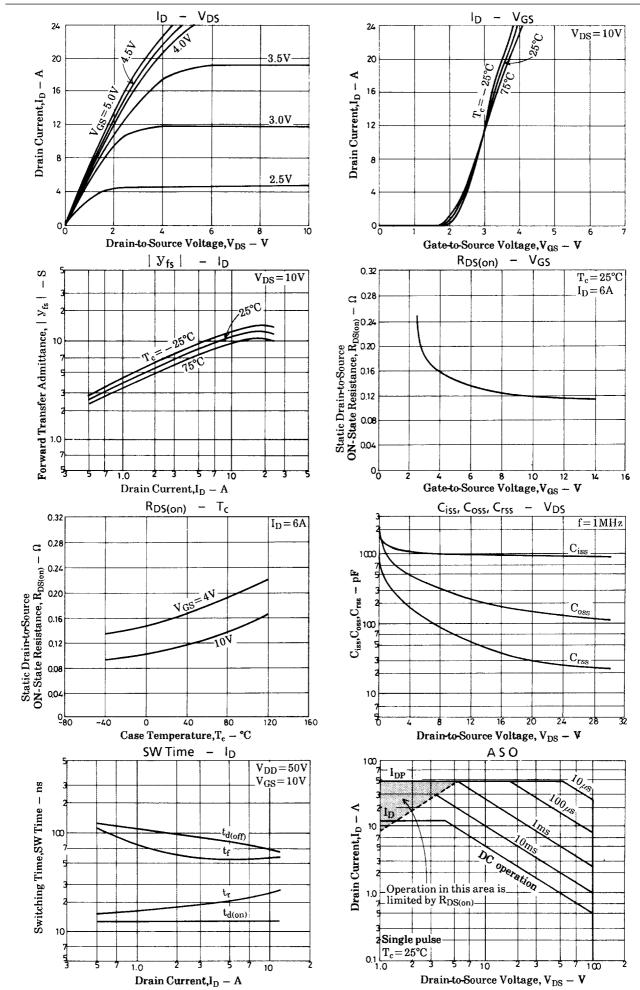
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		100	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±15	V
Drain Current (DC)	۱ <sub>D</sub>		12	A
Drain Current (Pulse)	I <sub>DP</sub>	PW≤10µs, duty cycle≤1%	48	A
Allowable Power Dissipation	PD		1.65	W
		Tc=25°C	50	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

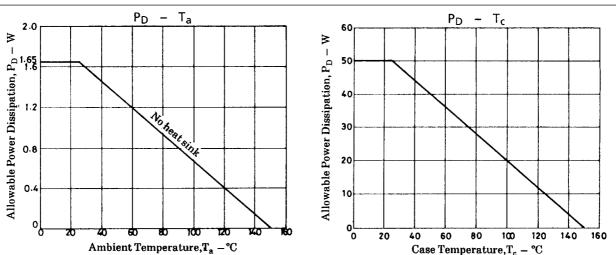
## Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V <sub>(BR)</sub> DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	100			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	I <sub>G</sub> =±100μA, V <sub>DS</sub> =0	±15			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =100V, V <sub>GS</sub> =0			100	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±12V, V <sub>DS</sub> =0			±10	μA
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.0		2.0	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =6A	6	9.5		S
Static Drain-to-Source ON-State Resistance	R <sub>DS(on)</sub>	ID=6A, VGS=10V		0.12	0.16	Ω
	R <sub>DS(on)</sub>	ID=6A, VGS=4V		0.16	0.22	Ω
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		950		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		150		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		30		pF
Turn-ON Delay Time	<sup>t</sup> d(on)	See specified Test Circuit		13		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit		22		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		80		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		55		ns
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =12A, V <sub>GS</sub> =0		1.0	1.5	V

## Switching Time Test Circuit







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